

ESH2PB, ESH2PC, ESH2PD

Vishay General Semiconductor

AUTOMOTIVE

RoHS

COMPLIANT

HALOGEN FREE

High Current Density Surface-Mount Ultrafast Rectifiers



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2.0 A				
V _{RRM}	100 V, 150 V, 200 V				
I _{FSM}	50 A				
t _{rr}	25 ns				
V _F at I _F = 2 A	0.75 V				
T _J max.	175 °C				
Package	SMP (DO-220AA)				
Circuit configuration	Single				

FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- · Glass passivated pellet chip junction
- · Ultrafast recovery times for high frequency
- Low forward voltage drop, low power losses
- Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of AC/DC and DC/DC converters in high temperature for both consumer and automotive applications.

MECHANICAL DATA

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and automotive grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix

meets JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT	
Device marking code		P2B	P2C	P2D		
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	2.0			Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50			А	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous	I _E = 2 A	T _J = 25 °C	V _E (1)	0.90	0.98	V	
forward voltage	I _F = 2 A	T _J = 125 °C	V F ('')	0.75	0.82	V	
Maximum reverse current at		T _J = 25 °C	I _R ⁽²⁾	0.2	1.0	μА	
rated V _R		T _J = 125 °C		12.6	25		
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	-	25	ns	
Typical reverse recovery time	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	t _{rr}	25	-	- ns	
		T _J = 100 °C		35	-		
Typical stored charge	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	Q _{rr}	10	-	nC	
		T _J = 100 °C		15	-		
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	-	pF	

Notes

 $^{(1)}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT	
	R _{0JA} (1)	80				
Typical thermal resistance	R _{θJL} ⁽¹⁾	15			°C/W	
	R ₀ JC (1)		22			

Note

(1) Thermal resistance from junction to ambient and junction to lead mounted on PCB with 6.0 mm x 6.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH2PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
ESH2PBHM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PBHM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

Note

(1) Automotive grade

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

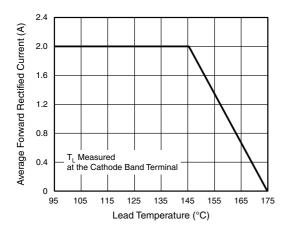


Fig. 1 - Maximum Forward Current Derating Curve

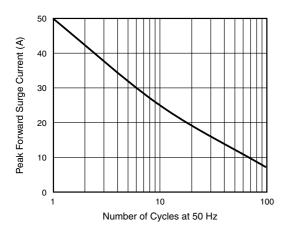


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

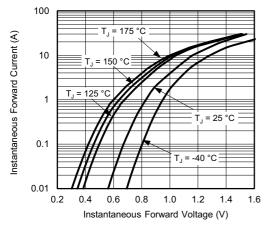


Fig. 3 - Typical Instantaneous Forward Characteristics

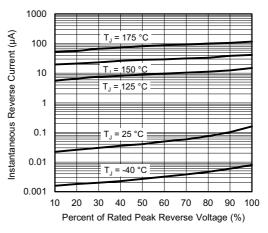


Fig. 4 - Typical Reverse Leakage Characteristics

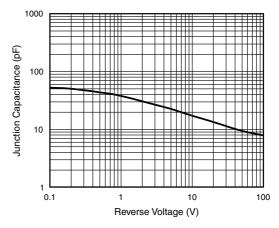


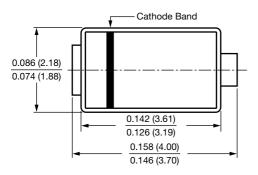
Fig. 5 - Typical Junction Capacitance

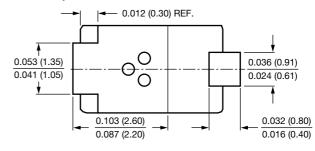
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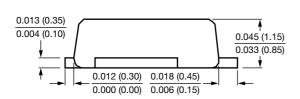
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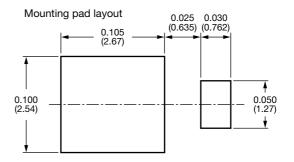
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMP (DO-220AA)











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